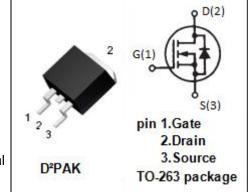


isc N-Channel MOSFET Transistor

PSMN1R5-30BLE

FEATURES

- Drain Current –I_D= 120A@ T_C=25 °C
- · Drain Source Voltage-
 - : V_{DSS}= 30V(Min)
- · Static Drain-Source On-Resistance
 - : $R_{DS(on)} = 1.5m \Omega (Max)$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



DESCRIPTION

• Designed for use in switch mode power supplies and general purpose applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	30	V
V _{GS}	Gate-Source Voltage-Continuous	±20	V
I _D	Drain Current-Continuous	120	Α
I _{DM}	Drain Current-Single Pluse	1521	Α
P _D	Total Dissipation @T _C =25℃	401	W
TJ	Max. Operating Junction Temperature	-55~175	$^{\circ}$
T _{stg}	Storage Temperature	-55~175	$^{\circ}$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	0.37	°C/W

	B	K		L S
J F	ון ע		R	V
		m	m	1
	DIM	MIN	MAX	1
	A	1	0	
	В	6.6	6.8	
	C	15.23	15.25	
	D	10.15	10.17]
	F	0.76	0.78	
	G	1.26	1.28 1.6	
	H	1.4		
	J	1.33	1.35	1
	K	0.4	0.6	- 0
	L	4.6	4.8	
	0	8.69	8.71	-
	R	5.28	5.30	-
	S	1.26	1.28	1
	U	0.0	0.2	
		0.27	0.20	1
	W	0.37 2.80	0.39 2.82	-

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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 0.25mA	30		V
V _{GS(th)}	Gate Threshold Voltage	V_{DS} = V_{GS} ; I_D = 1mA	1.3	2.15	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 25A		1.5	mΩ
Igss	Gate-Body Leakage Current	V _{GS} = ±16V;V _{DS} = 0		±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 30V; V _{GS} = 0		10	μА
V _{SD}	Forward On-Voltage	I _S = 25A; V _{GS} = 0		1.2	V

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